TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSIII)

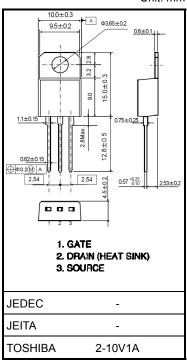
# TK70D06J1

#### Switching Regulator Application

- High-Speed switching
- Small gate charge: Qg = 87 nC (typ.)
- Low drain-source ON resistance:  $R_{DS (ON)} = 5.1 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: |Y<sub>fs</sub>| = 80 S (typ.)
- Low leakage current:  $I_{DSS}$  = 10  $\mu$ A (max) (V<sub>DS</sub> = 60 V)
- Enhancement-mode:  $V_{th}$  = 1.1 to 2.3 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage	)	V <sub>DSS</sub>	60	V	
Drain-gate voltage (F	R <sub>GS</sub> = 20 kΩ)	V <sub>DGR</sub>	60	V	
Gate-source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC (Note 1)	Ι <sub>D</sub>	70	٨	
	Pulse (Note 1)	I <sub>DP</sub>	280	A	
Drain power dissipat	ion (Tc = $25^{\circ}$ C)	PD	140	W	
Single pulse avalance	he energy (Note 2)	EAS	751	mJ	
Avalanche current		I <sub>AR</sub>	70	А	
Repetitive avalanche	e energy (Note 3)	E <sub>AR</sub>	10.3	mJ	
Channel temperature	9	T <sub>ch</sub>	150	°C	
Storage temperature	range	T <sub>stg</sub>	-55~150	°C	



Weight: 1.35 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	0.89	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	83.3	°C/W

Note 1: Ensure that the channel & lead temperature does not exceed 150°C.

Note 2: V\_{DD} = 25 V, T\_{ch} = 25^{\circ}C, L = 200 \ \mu\text{H}, \text{ I}\_{AR} = 70 \text{ A}, \text{ R}\_{G} = 1 \ \Omega

Note 3: Repetitive rating: pulse width limited by maximum channel temperature.

This transistor is an electrostatic-sensitive device. Handle with care.





Unit: mm

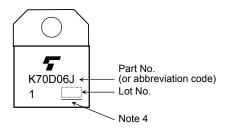
#### **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 16~V,~V_{DS}=0~V$	_	—	±10	μA
Drain cut-OFF current		I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		_	10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	60	—	_	v
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	45	_	_	
Gate threshold vo	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	1.1	—	2.3	V
Drain-source ON resistance		Decker	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 35 \text{A}$		5.8	7.6	- mΩ
		R <sub>DS</sub> (ON)	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 35 \text{ A}$		5.1	6.4	
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 35 \text{ A}$	40	80	_	S
Input capacitance	Input capacitance C <sub>iss</sub>				5450		
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS}=10V,V_{GS}=0~V,f=1~MHz$	_	320	_	pF
Output capacitance		C <sub>oss</sub>			1420		
Switching time	Rise time	tr	$V_{GS}^{10 \text{ V}} \downarrow \downarrow$	_	9	_	- ns
	Turn-ON time	t <sub>on</sub>			24		
	Fall time	t <sub>f</sub>			21		
	Turn-OFF time	t <sub>off</sub>			106		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD}\simeq 48~V,~V_{GS}=5~V,~I_D=70A$	_	47	_	
			$V_{DD}\simeq 48~V,~V_{GS}=10~V,~I_D=70A$	_	87	_	
Gate-source charge 1		Q <sub>gs1</sub>	$V_{DD} \simeq 48 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 70 \text{ A}$		16	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>		_	19	_	
Gate switch charge		Q <sub>sw</sub>	]		30	_	

#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_		70	А
Pulse drain reverse current (Note 1)	IDRP	—	_		280	А
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 70 \text{ A}, V_{GS} = 0 \text{ V}$	_	-1.0	-1.2	V
Reverse recovery time	trr	$I_{DR} = 70 \text{ A}, V_{GS} = 0 \text{ V},$	_	60	_	ns
Reverse recovery charge	Q <sub>rr</sub>	$dI_{DR}/dt = 50 \text{ A}/\mu\text{s}$	_	51	_	nC

#### Marking



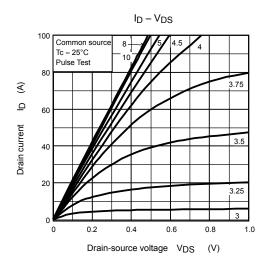
Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

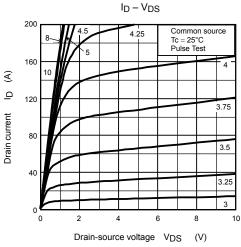
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

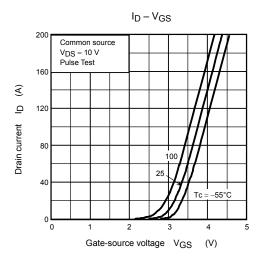
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

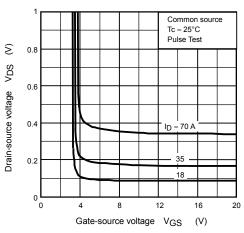
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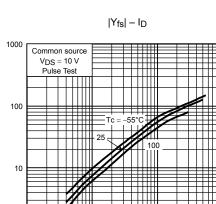
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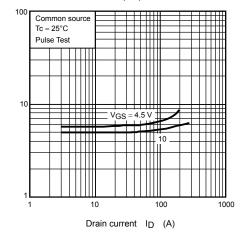


(S)

Forward transfer admittance |Y<sub>fs</sub>|

1 L 0.1

RDS (ON) - ID





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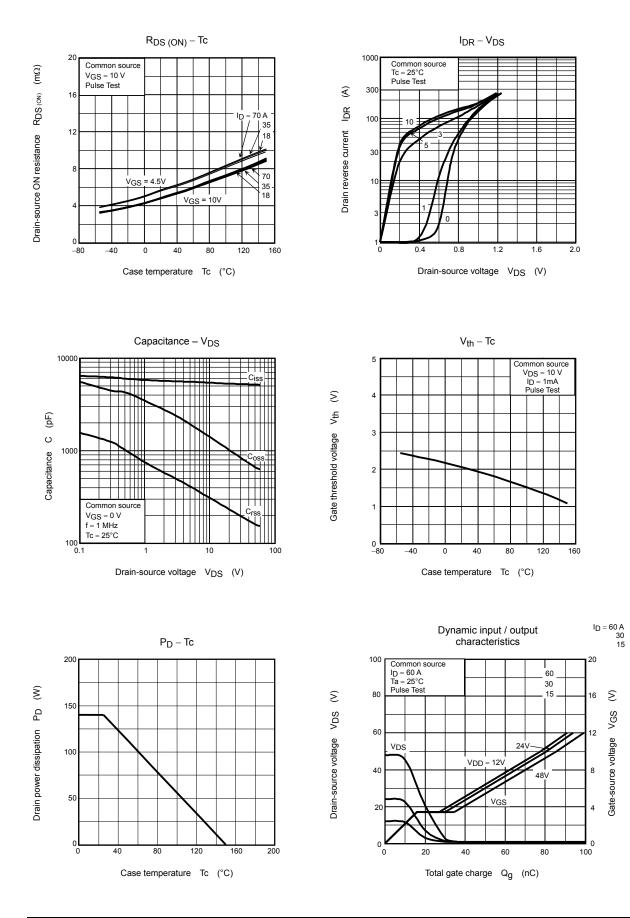
Drain current ID (A)

100

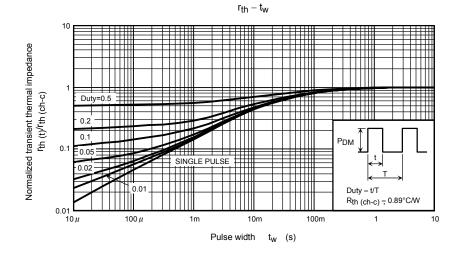
(MD)

Drain-source ON resistance RDS (ON)

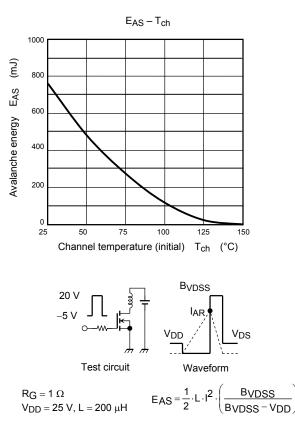
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SAFE OPERATING AREA 1000 ID max (pulse) 00 ms 100 ID ma: 3 <u>\_</u> 10 DC OPEATION Drain current  $Tc = 25^{\circ}C$ ※ Single pulse Ta=25°C 0.1 Curves must be derated linearly with increase in V<sub>DSS</sub> max temperature. 0.01 10 100 1 Drain-source voltage V<sub>DS</sub> (V)



## <u>TOSHIBA</u>

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